

Small Signal Fast Switching Diode

Features

- Silicon epitaxial planar diodes
- Low forward voltage drop
- High forward current capability
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



94 9371

Applications

- High speed switch and general purpose use in computer and industrial applications

Mechanical Data

Case: MiniMELF glass case (SOD80)

Weight: approx. 31 mg

Cathode band color: black

Packaging codes/options:

GS18/10 k per 13" reel (8 mm tape), 10 k/box

GS08/2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Ordering code	Type Marking	Remarks
LL4150	LL4150-GS18 or LL4150-GS08	-	Tape and Reel

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V_{RRM}	50	V
Reverse voltage		V_R	50	V
Peak forward surge current	$t_p = 1\text{ }\mu\text{s}$	I_{FSM}	4	A
Forward continuous current		I_F	600	mA
Average forward current	$V_R = 0$	I_{FAV}	300	mA
Power dissipation		P_{tot}	500	mW

Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	on PC board 50 mm x 50 mm x 1.6 mm	R_{thJA}	300	K/W
Junction temperature		T_j	175	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 65 to + 175	$^{\circ}\text{C}$

Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = 1\text{ mA}$	V_F	540		620	mV
	$I_F = 10\text{ mA}$	V_F	660		740	mV
	$I_F = 50\text{ mA}$	V_F	760		860	mV
	$I_F = 100\text{ mA}$	V_F	820		920	mV
	$I_F = 200\text{ mA}$	V_F	870		1000	mV
Reverse current	$V_R = 50\text{ V}$	I_R			100	nA
	$V_R = 50\text{ V}, T_j = 150\text{ }^{\circ}\text{C}$	I_R			100	μA
Diode capacitance	$V_R = 0, f = 1\text{ MHz}, V_{HF} = 50\text{ mV}$	C_D			2.5	pF
Reverse recovery time	$I_F = I_R = 10\text{ to }100\text{ mA},$ $i_R = 0.1 \times I_R, R_L = 100\text{ }\Omega$	t_{rr}			4	ns

Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

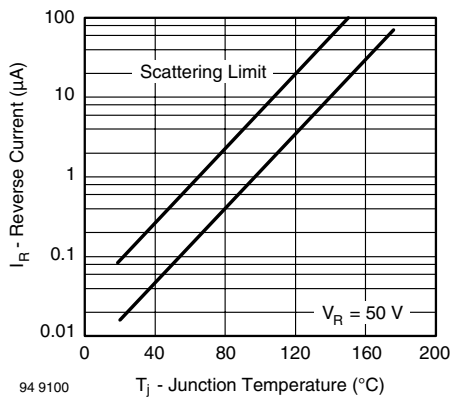


Figure 1. Reverse Current vs. Junction Temperature

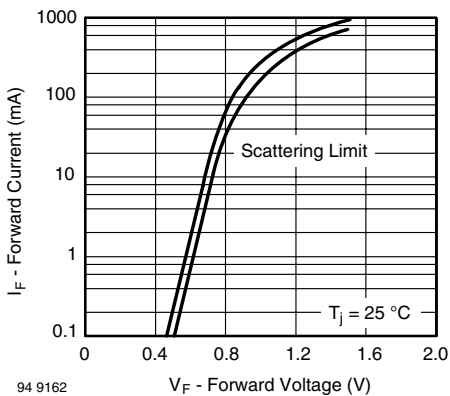
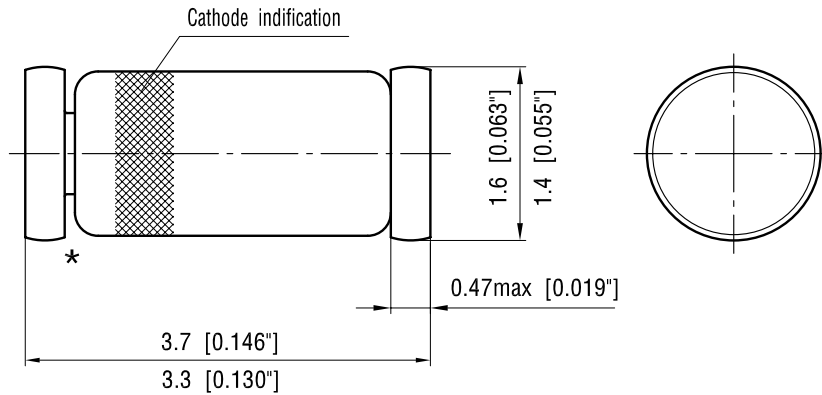


Figure 2. Forward Current vs. Forward Voltage

Package Dimensions in millimeters (inches): SOD80



* The gap between plug and glass can be either on cathode or anode side

foot print recommendation:

